RENESAS

DATASHEET

ISL8840A, ISL8841A, ISL8842A, ISL8843A, ISL8844A, ISL8845A High Performance Industry Standard Single-Ended Current Mode PWM Controller

FN6320 Rev 3.00 April 18, 2007

The ISL884xA is a high performance drop-in replacement for the popular 28C4x and 18C4x PWM controllers suitable for a wide range of power conversion applications including boost, flyback, and isolated output configurations. Its fast signal propagation and output switching characteristics make this an ideal product for existing and new designs.

Features include 30V operation, low operating current, $90\mu A$ start-up current, adjustable operating frequency to 2MHz, and high peak current drive capability with 20ns rise and fall times.

Pinout

ISL8840A, ISL8841A, ISL8842A, ISL8843A, ISL8844A, ISL8845A (8 LD SOIC, MSOP) TOP VIEW

Features

- 1A MOSFET gate driver
- 90 μ A start-up current, 125 μ A maximum
- 35ns propagation delay current sense to output
- Fast transient response with peak current mode control
- 30V operation
- Adjustable switching frequency to 2MHz
- 20ns rise and fall times with 1nF output load
- Trimmed timing capacitor discharge current for accurate deadtime/maximum duty cycle control
- 1.5MHz bandwidth error amplifier
- Tight tolerance voltage reference over line, load and temperature
- ±3% current limit threshold
- Pb-free plus anneal available and ELV, WEEE, RoHS Compliant

Applications

- Telecom and datacom power
- Wireless base station power
- File server power
- Industrial power systems
- PC power supplies
- Isolated buck and flyback regulators
- Boost regulators

Ordering Information

Ordering Information (Continued)

*Add "-T" suffix for tape and reel.

NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Functional Block Diagram

Typical Application - 48V Input Dual Output Flyback

FN6320 Rev 3.00
April 18, 2007 April 18, 2007 FN6320 Rev 3.00

RENESAS

ISL8840A, ISL8841A, ISL8842A, ISL8843A, ISL8844A, ISL8845A

ISL8840A, ISL8841A, ISL8842A, ISL8843A, ISL8844A, ISL8845A

Typical Application - Boost Converter

Absolute Maximum Ratings **Thermal Information**

Operating Conditions

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

+150°C max junction temperature is intended for short periods of time to prevent shortening the lifetime. Constantly operated at +150°C may shorten the life of the part. NOTES:

1. θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Technical Brief TB379 for details.

2. All voltages are with respect to GND.

Electrical Specifications ISL884xAA - Recommended operating conditions unless otherwise noted. Refer to Block Diagram and Typical Application schematic on[page 3](#page-2-0) and [page 4.](#page-3-0) V_{DD} = 15V, R_T = 10k Ω , C_T = 3.3nF, **T_A** = -40 to +105°C

(Note [3](#page-6-0)). Typical values are at T_A = +25°C

Electrical Specifications ISL884xAA - Recommended operating conditions unless otherwise noted. Refer to Block Diagram and Typical Application schematic onpage 3 and page 4. V_{DD} = 15V, R_T = 10k Ω , C_T = 3.3nF, T_A = -40 to +105°C (Note 3). Typical values are at T_A = +25°C (Continued)

NOTES:

3. Specifications at -40°C and +105°C are guaranteed by +25°C test with margin limits.

4. This is the V_{DD} current consumed when the device is active but not switching. Does not include gate drive current.

5. These parameters, although guaranteed, are not 100% tested in production.

6. Adjust V_{DD} above the start threshold and then lower to 15V.

Electrical Specifications ISL884xAM - Recommended operating conditions unless otherwise noted. Refer to Block Diagram and Typical Application schematic. V_{DD} = 15V, RT = 10k Ω , CT = 3.3nF, T_A = -55 to +125°C (Note [7](#page-8-0)), Typical values are at T_A = +25°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
UNDERVOLTAGE LOCKOUT					
START Threshold (ISL8840A, ISL8841A)		6.5	7.0	7.5	\vee
START Threshold (ISL8843A, ISL8845A)		8.0	8.4	9.0	V
START Threshold (ISL8842A, ISL8844A)	(Note 10)	13.3	14.3	15.3	V
STOP Threshold (ISL8840A, ISL8841A)		6.1	6.6	6.9	V
STOP Threshold (ISL8843A, ISL8845A)		7.3	7.6	8.0	V
STOP Threshold (ISL8842A, ISL8844A)		8.0	8.8	9.6	V
Hysteresis (ISL8840A, ISL8841A)			0.4		\vee
Hysteresis (ISL8843A, ISL8845A)		$\overline{}$	0.8	$\overline{}$	V
Hysteresis (ISL8842A, ISL8844A)		$\overline{}$	5.4		\vee
Startup Current, I _{DD}	V _{DD} < START Threshold	$\overline{}$	90	125	μA
Operating Current, I _{DD}	(Note 8)	$\overline{}$	2.9	4.0	mA
Operating Supply Current, I _D	Includes 1nF GATE loading	$\overline{}$	4.75	5.5	mA
REFERENCE VOLTAGE					
Overall Accuracy	Over line (V_{DD} = 12V to 30V), load, temperature	4.900	5.000	5.050	V
Long Term Stability	T_A = +125°C, 1000 hours (Note 9)	\blacksquare	5	\overline{a}	mV
Current Limit, Sourcing		-20	$\overline{}$	\overline{a}	mA
Current Limit, Sinking		5			mA
CURRENT SENSE					
Input Bias Current	$V_{CS} = 1V$	-1.0		1.0	μA
CS Offset Voltage	V_{CS} = 0V (Note 9)	95	100	105	mV
COMP to PWM Comparator Offset Voltage	V_{CS} = 0V (Note 9)	0.80	1.15	1.30	V
Input Signal, Maximum		0.97	1.00	1.03	V
Gain, $A_{CS} = \Delta V_{COMP}/\Delta V_{CS}$	$0 < V_{CS}$ < 910mV, V_{FB} = 0V	2.5	3.0	3.5	V/V
CS to OUT Delay		$\overline{}$	35	60	ns
ERROR AMPLIFIER					
Open Loop Voltage Gain	(Note 9)	60	90	$\overline{}$	dB
Unity Gain Bandwidth	(Note 9)	1.0	1.5		MHz
Reference Voltage	$VFB = VCOMP$	2.460	2.500	2.535	V
FB Input Bias Current	$V_{FB} = 0V$	-1.0	-0.2	1.0	μA
COMP Sink Current	$V_{\text{COMP}} = 1.5V, V_{\text{FB}} = 2.7V$	1.0	$\frac{1}{2}$		mA
COMP Source Current	$V_{COMP} = 1.5V, V_{FB} = 2.3V$	-0.4	$\overline{}$	$\overline{}$	mA
COMP VOH	$V_{FB} = 2.3V$	4.80	$\overline{}$	VREF	V
COMP VOL	$V_{FB} = 2.7V$	0.4	$\overline{}$	1.0	V
PSRR	Frequency = 120Hz, V_{DD} = 12V to 30V (Note 9)	60	80		dB
OSCILLATOR					
Frequency Accuracy	Initial, T_A = +25°C	48	51	53	kHz
Frequency Variation with V _{DD}	T_A = +25°C, (f _{30V} - f _{10V})/f _{30V}	$\overline{}$	0.2	1.0	%
Temperature Stability	(Note 9)	$\overline{}$	$\overline{}$	5	$\%$

Electrical Specifications ISL884xAM - Recommended operating conditions unless otherwise noted. Refer to Block Diagram and Typical Application schematic. V_{DD} = 15V, RT = 10k Ω , CT = 3.3nF, **T_A** = -55 to +125°C (Note 7), Typical values are at T_A = +25°C (Continued)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS			
Amplitude, Peak to Peak	Static Test		1.75		V			
RTCT Discharge Voltage (Valley Voltage)	Static Test	$\overline{}$	1.0		V			
Discharge Current	$RTCT = 2.0V$	6.2	8.0	8.5	m _A			
OUTPUT								
Gate VOH	V_{DD} - OUT, I_{OUT} = -200mA		1.0	2.0	V			
Gate VOL	OUT - GND, I_{OUT} = 200mA	$\overline{}$	1.0	2.0	\vee			
Peak Output Current	C_{OUT} = 1nF (Note 9)	$\overline{}$	1.0	$\overline{}$	A			
Rise Time	C_{OUT} = 1nF (Note 9)	$\overline{}$	20	40	ns			
Fall Time	C_{OUT} = 1nF (Note 9)		20	40	ns			
GATE VOL UVLO Clamp Voltage	V_{DD} = 5V, I_{LOAD} = 1mA	$\overline{}$	$\overline{}$	1.2	V			
PWM								
Maximum Duty Cycle (ISL8840A, ISL8842A, ISL8843A)	$COMP = VREF$	94.0	96.0		$\frac{0}{0}$			
Maximum Duty Cycle (ISL8841A, ISL8844A, ISL8845A)	$COMP = VREF$	47.0	48.0		$\frac{0}{0}$			
Minimum Duty Cycle	$COMP = GND$			0	$\%$			

NOTES:

7. Specifications at -55°C and +125°C are guaranteed by +25°C test with margin limits.

8. This is the V_{DD} current consumed when the device is active but not switching. Does not include gate drive current.

9. These parameters, although guaranteed, are not 100% tested in production.

10. Adjust V_{DD} above the start threshold and then lower to 15V.

Typical Performance Curves

Typical Performance Curves **(Continued)**

Pin Descriptions

RTCT - This is the oscillator timing control pin. The operational frequency and maximum duty cycle are set by connecting a resistor, RT, between VREF and this pin and a timing capacitor, CT, from this pin to GND. The oscillator produces a sawtooth waveform with a programmable frequency range up to 2.0MHz. The charge time, t_C , the discharge time, t_D , the switching frequency, f, and the maximum duty cycle, Dmax, can be approximated from the following equations:

$$
t_C \approx 0.533 \cdot RT \cdot CT \tag{EQ. 1}
$$

$$
t_D \approx -RT \cdot CT \cdot \ln\left(\frac{0.008 \cdot RT - 3.83}{0.008 \cdot RT - 1.71}\right)
$$
 (EQ. 2)

 $f = 1/(t_C + t_D)$ (EQ. 3)

$$
D = t_C \cdot f \tag{EQ.4}
$$

The formulae have increased error at higher frequencies due to propagation delays. Figure [4](#page-9-0) may be used as a guideline in selecting the capacitor and resistor values required for a given frequency.

COMP - COMP is the output of the error amplifier and the input of the PWM comparator. The control loop frequency compensation network is connected between the COMP and FB pins.

FB - The output voltage feedback is connected to the inverting input of the error amplifier through this pin. The non-inverting input of the error amplifier is internally tied to a reference voltage.

CS - This is the current sense input to the PWM comparator. The range of the input signal is nominally 0V to 1.0V and has an internal offset of 100mV.

GND - GND is the power and small signal reference ground for all functions.

OUT - This is the drive output to the power switching device. It is a high current output capable of driving the gate of a power

MOSFET with peak currents of 1.0A. This GATE output is actively held low when V_{DD} is below the UVLO threshold.

VDD - VDD is the power connection for the device. The total supply current will depend on the load applied to OUT. Total I_{DD} current is the sum of the operating current and the average output current. Knowing the operating frequency, f, and the MOSFET gate charge, Qg, the average output current can be calculated from:

$$
I_{\text{OUT}} = \text{Qg} \times \text{f} \tag{EQ.5}
$$

To optimize noise immunity, bypass V_{DD} to GND with a ceramic capacitor as close to the V_{DD} and GND pins as possible.

VREF - The 5.00V reference voltage output. +1.0/-1.5% tolerance over line, load and operating temperature. Bypass to GND with a 0.1μ F to 3.3μ F capacitor to filter this output as needed.

Functional Description

Features

The ISL884xA current mode PWM makes an ideal choice for low-cost flyback and forward topology applications. With its greatly improved performance over industry standard parts, it is the obvious choice for new designs or existing designs which require updating.

Oscillator

The ISL884xA has a sawtooth oscillator with a programmable frequency range to 2MHz, which can be programmed with a resistor from VREF and a capacitor to GND on the RTCT pin. (Please refer to Figure [4](#page-9-0) for the resistor and capacitance required for a given frequency.)

Soft-Start Operation

Soft-start must be implemented externally. One method, illustrated below, clamps the voltage on COMP.

FIGURE 5. SOFT-START

The COMP pin is clamped to the voltage on capacitor C1 plus a base-emitter junction by transistor Q1. C1 is charged from VREF through resistor R1 and the base current of Q1. At power-up C1 is fully discharged, COMP is at ~0.7V, and the duty cycle is zero. As C1 charges, the voltage on COMP increases, and the duty cycle increases in proportion to the voltage on C1. When COMP reaches the steady state operating point, the control loop takes over and soft start is complete. C1 continues to charge up to VREF and no longer affects COMP. During power down, diode D1 quickly discharges C1 so that the soft start circuit is properly initialized prior to the next power on sequence.

Gate Drive

The ISL884xA is capable of sourcing and sinking 1A peak current. To limit the peak current through the IC, an optional external resistor may be placed between the totem-pole output of the IC (OUT pin) and the gate of the MOSFET. This small series resistor also damps any oscillations caused by the resonant tank of the parasitic inductances in the traces of the board and the FET's input capacitance.

Slope Compensation

For applications where the maximum duty cycle is less than 50%, slope compensation may be used to improve noise immunity, particularly at lighter loads. The amount of slope compensation required for noise immunity is determined empirically, but is generally about 10% of the full scale current feedback signal. For applications where the duty cycle is greater than 50%, slope compensation is required to prevent instability.

Slope compensation may be accomplished by summing an external ramp with the current feedback signal or by subtracting the external ramp from the voltage feedback error signal. Adding the external ramp to the current feedback signal is the more popular method.

From the small signal current-mode model [\[1](#page-12-0)] it can be shown that the naturally-sampled modulator gain, Fm, without slope compensation, is in Equation [6](#page-10-0).

$$
Fm = \frac{1}{SnTsw}
$$
 (EQ. 6)

where Sn is the slope of the sawtooth signal and Tsw is the duration of the half-cycle. When an external ramp is added, the modulator gain becomes:

$$
Fm = \frac{1}{(Sn + Se)Tsw} = \frac{1}{m_c SnTsw}
$$
 (EQ. 7)

where Se is slope of the external ramp and

$$
m_c = 1 + \frac{Se}{Sn}
$$
 (EQ. 8)

The criteria for determining the correct amount of external ramp can be determined by appropriately setting the damping factor of the double-pole located at the switching frequency. The double-pole will be critically damped if the Q-factor is set to 1, over-damped for $Q < 1$, and under-damped for $Q > 1$. An under-damped condition may result in current loop instability.

$$
Q = \frac{1}{\pi (m_c (1 - D) - 0.5)}
$$
 (EQ. 9)

where D is the percent of on time during a switching cycle. Setting $Q = 1$ and solving for Se yields

$$
S_e = S_n \left(\left(\frac{1}{\pi} + 0.5 \right) \frac{1}{1 - D} - 1 \right)
$$
 (EQ. 10)

Since Sn and Se are the on time slopes of the current ramp and the external ramp, respectively, they can be multiplied by t_{ON} to obtain the voltage change that occurs during t_{ON} .

$$
V_e = V_n \left(\left(\frac{1}{\pi} + 0.5 \right) \frac{1}{1 - D} - 1 \right)
$$
 (EQ. 11)

where Vn is the change in the current feedback signal (ΔI) during the on time and Ve is the voltage that must be added by the external ramp.

For a flyback converter, Vn can be solved for in terms of input voltage, current transducer components, and primary inductance, yielding

$$
V_{e} = \frac{D \cdot T_{SW} \cdot V_{IN} \cdot R_{CS}}{L_{p}} \Big(\Big(\frac{1}{\pi} + 0.5 \Big) \frac{1}{1 - D} - 1 \Big) \qquad V
$$
\n(EQ. 12)

where R_{CS} is the current sense resistor, f_{sw} is the switching frequency, L_p is the primary inductance, V_{IN} is the minimum input voltage, and D is the maximum duty cycle.

The current sense signal at the end of the ON time for CCM operation is:

$$
V_{CS} = \frac{N_S \cdot R_{CS}}{N_P} \left(I_O + \frac{(1 - D) \cdot V_O \cdot f_{sw}}{2L_s} \right) \qquad V \tag{Eq. 13}
$$

where V_{CS} is the voltage across the current sense resistor, L_s is the secondary winding inductance, and I_O is the output current at current limit. Equation [13](#page-11-1) assumes the voltage drop across the output rectifier is negligible.

Since the peak current limit threshold is 1.00V, the total current feedback signal plus the external ramp voltage must sum to this value when the output load is at the current limit threshold.

$$
V_e + V_{CS} = 1 \tag{EQ.14}
$$

Substituting Equations [12](#page-10-1) and [13](#page-11-1) into Equation [14](#page-11-2) and solving for R_{CS} yields

$$
R_{CS} = \frac{1}{\frac{D \cdot f_{sw} \cdot V_{IN}}{L_p} \cdot \left(\frac{\frac{1}{\pi} + 0.5}{1 - D} - 1\right) + \frac{N_s}{N_p} \cdot \left(I_O + \frac{(1 - D) \cdot V_O \cdot f_{sw}}{2L_s} \right)}
$$
(EQ. 15)

Adding slope compensation is accomplished in the ISL884xA using an external buffer transistor and the RTCT signal. A typical application sums the buffered RTCT signal with the current sense feedback and applies the result to the CS pin as shown in Figure [6.](#page-11-0)

FIGURE 6. SLOPE COMPENSATION

Assuming the designer has selected values for the RC filter (R₆ and C₄) placed on the CS pin, the value of R₉ required to add the appropriate external ramp can be found by superposition.

$$
V_{e} = \frac{2.05D \cdot R_{6}}{R_{6} + R_{9}} \qquad V \qquad (EQ. 16)
$$

The factor of 2.05 in Equation [16](#page-11-3) arises from the peak amplitude of the sawtooth waveform on RTCT minus a base-emitter junction drop. That voltage multiplied by the maximum duty cycle is the voltage source for the slope compensation. Rearranging to solve for R_{g} yields:

$$
R_g = \frac{(2.05D - V_e) \cdot R_6}{V_e} \qquad \Omega \tag{EQ.17}
$$

The value of R_{CS} determined in Equation [15](#page-11-4) must be rescaled so that the current sense signal presented at the CS pin is that predicted by Equation [13](#page-11-1). The divider created by R_6 and R_9 makes this necessary.

$$
R'_{CS} = \frac{R_6 + R_9}{R_9} \cdot R_{CS}
$$
 (EQ. 18)

Example:

 V_{IN} = 12V

 V_{Ω} = 48V

 L_S = 800 μ H

 $Ns/Np = 10$

 $Lp = 8.0\mu H$

 I_{Ω} = 200 mA

Switching Frequency, f_{SW} = 200kHz

Duty Cycle, $D = 28.6\%$

 R_6 = 499 Ω

Solve for the current sense resistor, R_{CS} , using Equation [15](#page-11-4).

 R_{CS} = 295m Ω

Determine the amount of voltage, Ve, that must be added to the current feedback signal using Equation [12](#page-10-1).

 $Ve = 92.4mV$

Using Equation [17,](#page-11-5) solve for the summing resistor, R₉, from CT to CS.

 $R_g = 2.67k\Omega$

Determine the new value of R_{CS} (R_{CS}) using Equation [18](#page-11-6).

 R'_{CS} = 350m Ω

Additional slope compensation may be considered for design margin. The above discussion determines the minimum external ramp that is required. The buffer transistor used to create the external ramp from RTCT should have a sufficiently high gain (>200) so as to minimize the required base current. Whatever base current is required reduces the charging current into RTCT and will reduce the oscillator frequency.

Fault Conditions

A Fault condition occurs if VREF falls below 4.65V. When a Fault is detected OUT is disabled. When VREF exceeds 4.80V, the Fault condition clears, and OUT is enabled.

Ground Plane Requirements

Careful layout is essential for satisfactory operation of the device. A good ground plane must be employed. A unique section of the ground plane must be designated for high di/dt currents associated with the output stage. V_{DD} should be bypassed directly to GND with good high frequency capacitors.

References

[1] Ridley, R., "A New Continuous-Time Model for Current Mode Control", IEEE Transactions on Power Electronics, Vol. 6, No. 2, April 1991.

© Copyright Intersil Americas LLC 2005-2007. All Rights Reserved. All trademarks and registered trademarks are the property of their respective owners.

For additional products, see [www.intersil.com/en/products.html](http://www.intersil.com/en/products.html?utm_source=Intersil&utm_medium=datasheet&utm_campaign=disclaimer-ds-footer)

[Intersil products are manufactured, assembled and tested utilizing ISO9001 quality systems as noted](http://www.intersil.com/en/products.html?utm_source=Intersil&utm_medium=datasheet&utm_campaign=disclaimer-ds-footer) in the quality certifications found at [www.intersil.com/en/support/qualandreliability.html](http://www.intersil.com/en/support/qualandreliability.html?utm_source=Intersil&utm_medium=datasheet&utm_campaign=disclaimer-ds-footer)

Intersil products are sold by description only. Intersil may modify the circuit design and/or specifications of products at any time without notice, provided that such modification does not, in Intersil's sole judgment, affect the form, fit or function of the product. Accordingly, the reader is cautioned to verify that datasheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

For information regarding Intersil Corporation and its products, see [www.intersil.com](http://www.intersil.com?utm_source=intersil&utm_medium=datasheet&utm_campaign=disclaimer-ds-footer)

April 18, 2007

Small Outline Plastic Packages (SOIC)

NOTES:

- 1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M**-**1982.
- 3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- 4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- 9. The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
- 10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

M8.15 (JEDEC MS-012-AA ISSUE C) 8 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE

Rev. 1 6/05

Mini Small Outline Plastic Packages (MSOP)

NOTES:

- 1. These package dimensions are within allowable dimensions of JEDEC MO-187BA.
- 2. Dimensioning and tolerancing per ANSI Y14.5M**-**1994.
- 3. Dimension "D" does not include mold flash, protrusions or gate burrs and are measured at Datum Plane. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- 4. Dimension "E1" does not include interlead flash or protrusions and are measured at Datum Plane. [-H-]Interlead flash and protrusions shall not exceed 0.15mm (0.006 inch) per side.
- 5. Formed leads shall be planar with respect to one another within 0.10mm (0.004) at seating Plane.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- 9. Dimension "b" does not include dambar protrusion. Allowable dambar protrusion shall be 0.08mm (0.003 inch) total in excess of "b" dimension at maximum material condition. Minimum space between protrusion and adjacent lead is 0.07mm (0.0027 inch).
- 10. Datums $-A -$ and $B -$ to be determined at Datum plane . - H -
- 11. Controlling dimension: MILLIMETER. Converted inch dimensions are for reference only.

M8.118 (JEDEC MO-187AA) 8 LEAD MINI SMALL OUTLINE PLASTIC PACKAGE

